

Phase Control Thyristor

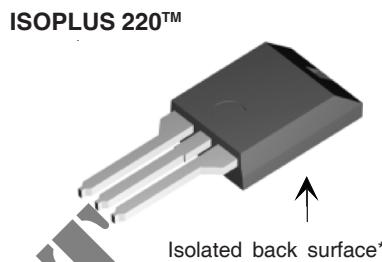
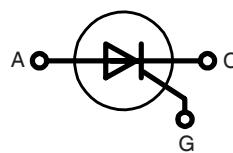
ISOPLUS220™

Electrically Isolated Back Surface

$V_{RRM} = 800/1200 \text{ V}$
 $I_{T(RMS)} = 35 \text{ A}$
 $I_{T(AV)M} = 23 \text{ A}$

Preliminary Data Sheet

V_{RSM}	V_{RRM}	Type
V_{DSM}	V_{DRM}	
V	V	
800	800	CS 29-08io1C
1200	1200	CS 29-12io1C



Symbol	Conditions	Maximum Ratings		Features
$I_{T(RMS)}$	$T_{VJ} = T_{VJM}$	35	A	
$I_{T(AV)M}$	$T_C = 95^\circ\text{C}$; 180° sine ($I_{T(RMS)}$ current limit)	23	A	
I_{TSM}	$T_{VJ} = 45^\circ\text{C}$; $t = 10 \text{ ms}$ (50 Hz), sine $V_R = 0 \text{ V}$ $t = 8.3 \text{ ms}$ (60 Hz), sine	200	A	
	$T_{VJ} = T_{VJM}$; $t = 10 \text{ ms}$ (50 Hz), sine $V_R = 0 \text{ V}$ $t = 8.3 \text{ ms}$ (60 Hz), sine	175	A	
		185	A	
I^2t	$T_{VJ} = 45^\circ\text{C}$; $t = 10 \text{ ms}$ (50 Hz), sine $V_R = 0 \text{ V}$ $t = 8.3 \text{ ms}$ (60 Hz), sine	200	A^2s	
		195	A^2s	
	$T_{VJ} = T_{VJM}$; $t = 10 \text{ ms}$ (50 Hz), sine $V_R = 0 \text{ V}$ $t = 8.3 \text{ ms}$ (60 Hz), sine	155	A^2s	
		145	A^2s	
$(di/dt)_{cr}$	$T_{VJ} = T_{VJM}$; $f = 50 \text{ Hz}$; $t_p = 200 \mu\text{s}$; $V_D = \frac{2}{3} V_{DRM}$; $I_G = 0.2 \text{ A}$; $di/dt = 0.2 \text{ A}/\mu\text{s}$	repetitive, $I_T = 40 \text{ A}$ non repetitive, $I_T = I_{T(AV)M}$	150	$\text{A}/\mu\text{s}$
			500	$\text{A}/\mu\text{s}$
$(dv/dt)_{cr}$	$T_{VJ} = T_{VJM}$; $R_{GK} = \infty$; method 1 (linear voltage rise)	$V_{DR} = \frac{2}{3} V_{DRM}$;	1000	$\text{V}/\mu\text{s}$
P_{GM}	$T_{VJ} = T_{VJM}$; $I_T = I_{T(AV)M}$;	$t_p = 30 \mu\text{s}$ $t_p = 300 \mu\text{s}$	5 2.5 0.5	W W W
P_{GAV}				
V_{RGM}			10	V
T_{VJ}			-40...+150	$^\circ\text{C}$
T_{VJM}			150	$^\circ\text{C}$
T_{stg}			-40...+150	$^\circ\text{C}$
V_{ISOL}	50/60 Hz RMS; $I_{ISOL} \leq 1 \text{ mA}$	2500		V~
T_L	1.6 mm from case; 10 s		260	$^\circ\text{C}$
F_c	Mounting force	11...65 / 2.4...11		N/lb
Weight		2		g

Symbol	Conditions	Characteristic Values		
I_R, I_D	$T_{VJ} = T_{VJM}$; $V_R = V_{RRM}$; $V_D = V_{DRM}$	\leq	2	mA
V_T	$I_T = 45 \text{ A}$; $T_{VJ} = 25^\circ\text{C}$	\leq	1.5	V
V_{T0}	For power-loss calculations only ($T_{VJ} = 125^\circ\text{C}$)	0.82	V	
r_T		16.5	$\text{m}\Omega$	
V_{GT}	$V_D = 6 \text{ V}$; $T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = -40^\circ\text{C}$	\leq	1.0	V
I_{GT}	$V_D = 6 \text{ V}$; $T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = -40^\circ\text{C}$	\leq	65	mA
I_{GD}	$T_{VJ} = T_{VJM}$; $V_D = \frac{2}{3} V_{DRM}$	\leq	0.2	V
I_{GD}		\leq	5	mA
I_L	$T_{VJ} = 25^\circ\text{C}$; $t_p = 10 \mu\text{s}$; $I_G = 0.2 \text{ A}$; $dI_G/dt = 0.2 \text{ A}/\mu\text{s}$	\leq	150	mA
I_H	$T_{VJ} = 25^\circ\text{C}$; $V_D = 6 \text{ V}$; $R_{GK} = \infty$	\leq	50	mA
t_{gd}	$T_{VJ} = 25^\circ\text{C}$; $V_D = \frac{1}{2} V_{DRM}$; $I_G = 0.2 \text{ A}$; $dI_G/dt = 0.2 \text{ A}/\mu\text{s}$	\leq	2	μs
R_{thJC}	DC current		1.2	K/W
R_{thCK}	DC current	typical	0.6	K/W
a	Max. acceleration, 50 Hz		50	m/s^2

See CS 30..io1 data sheet for electrical characteristic curves.

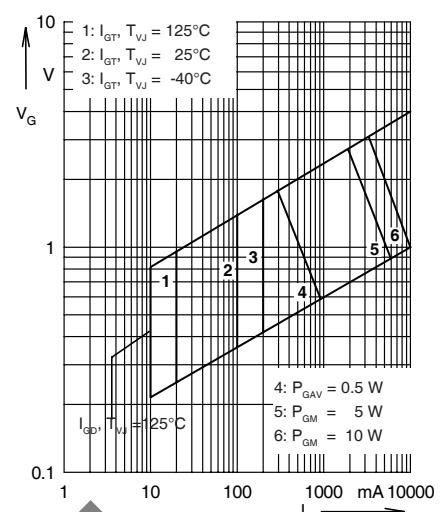
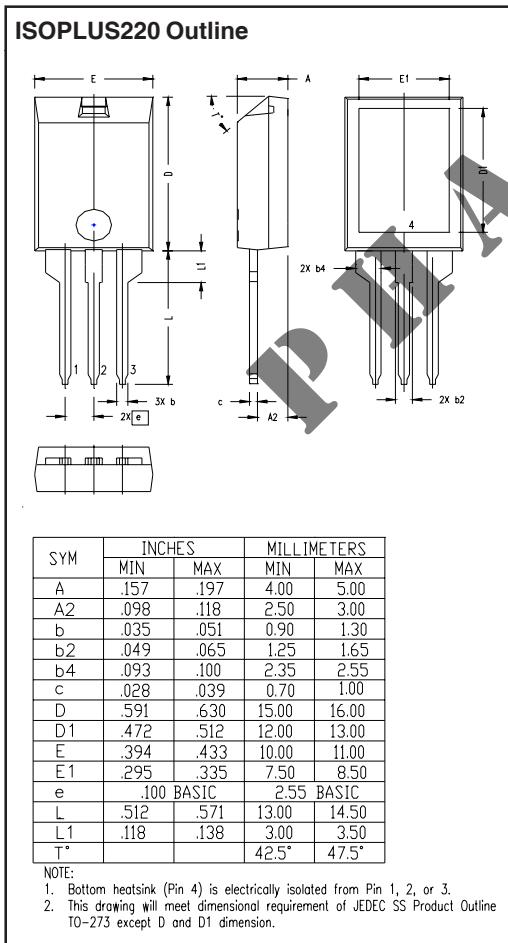


Fig. 1 Gate trigger range

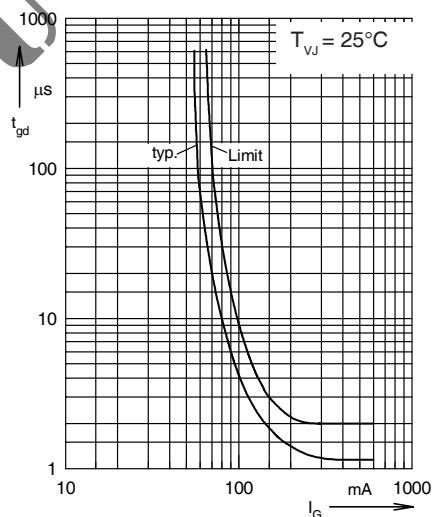


Fig. 2 Gate controlled delay time t_{gd}

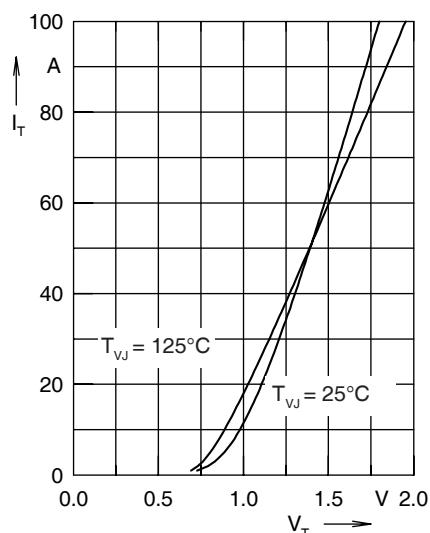


Fig. 3 Forward characteristics

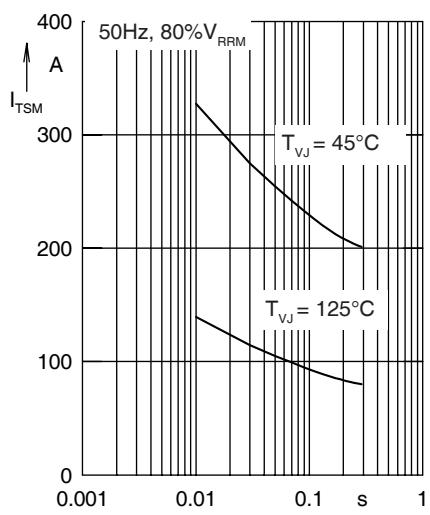


Fig. 4 Surge overload current
 $I_{TS M}$: crest value, t : duration

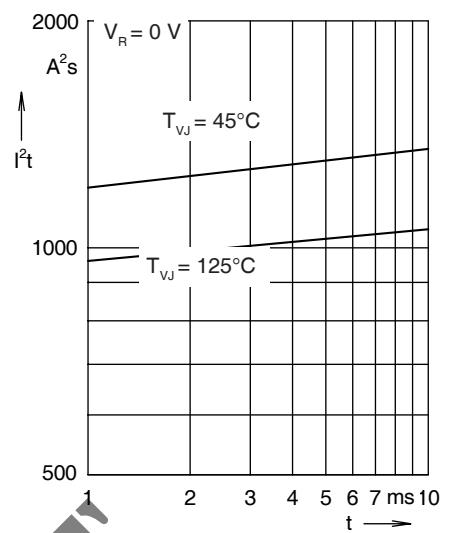


Fig. 5 I^2t versus time (1-10 ms)

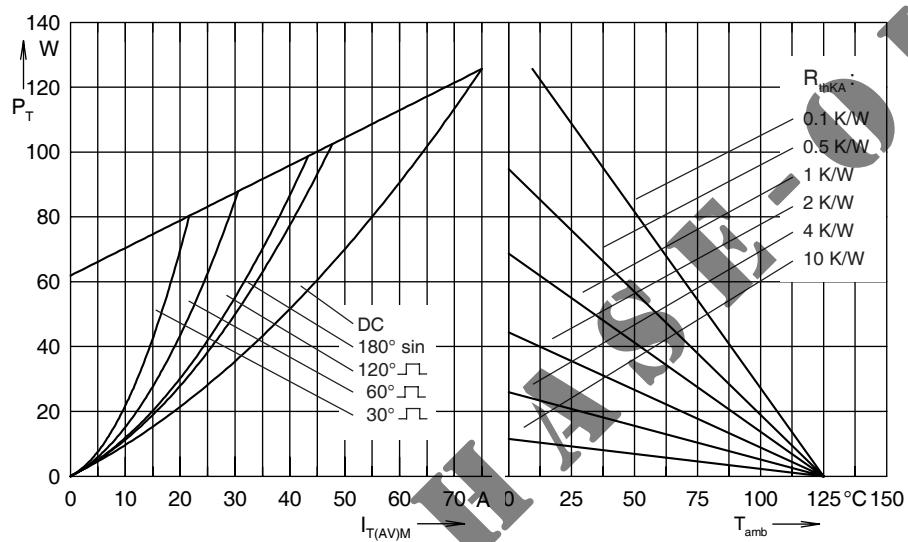


Fig. 6 Power dissipation versus forward current and ambient temperature